

isc Silicon NPN Power Transistor

BD735

DESCRIPTION

- DC Current Gain -
- : h_{FE} = 40(Min.)@ I_C= 20mA
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 35V(Min.)
- Complement to Type BD736
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

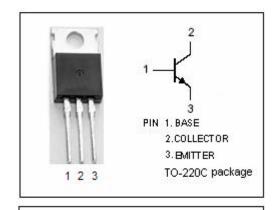


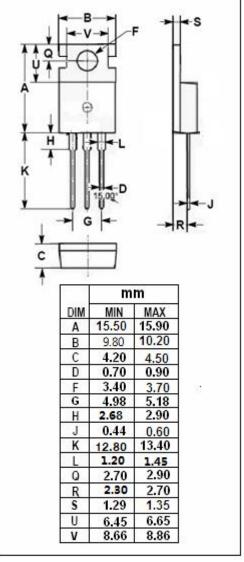
APPLICATIONS

· Designed for amplifier and switching applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	35	V	
Vceo	Collector-Emitter Voltage	35	V	
V_{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	4	А	
Ісм	Collector Current-Peak	7	А	
I _B	Base Current-Continuous	1	А	
P _C	Collector Power Dissipation @ Ta=25°C	2	W	
	Collector Power Dissipation @ Tc=25°C	40		
TJ	Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	35		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 0.1mA; I _E = 0	35		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	5		V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 0.2A		0.6	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 2A; V _{CE} = 1V		1.1	V
Ices	Collector Cutoff Current	V _{CE} = 35V; V _{BE} = 0		0.2	mA
h _{FE-1}	DC Current Gain	I _C = 20mA; V _{CE} = 4V	40		
h _{FE-2}	DC Current Gain	I _C = 2A; V _{CE} = 1V	40		

NOTICE:

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